E lectronic P roperties of Transuranium C om pounds with H oC oG a₅-Type Tetragonal C rystal Structure

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By using a relativistic linear augmented-plane-wavemethod with the one-electron potential in the local-density approximation, we investigate energy band structures and the Ferm i surfaces of transuranium compounds NpTG a_5 , PuTG a_5 , and AmCoG a_5 with transition metal atoms T. It is found in common that the energy bands in the vicinity of the Ferm i level are mainly due to the large hybridization between 5f and Ga 4p electrons. For PuTG a_5 , we observe several cylindrical sheets of Ferm i surfaces with large volume for T = Co, Rh, and Ir. The de H aas-van A phen (dHvA) frequencies are theoretically estimated for PuCoG a_5 . It is also found that the Ferm i surfaces of N pFeG a_5 , N pC oG a_5 , and N pN iG a_5 are similar to those of UC oG a_5 , UN iG a_5 , and PuCoG a_5 , the Ferm i surfaces are found to consist of large cylindrical electron sheets and small closed hole sheets, similar to PuC oG a_5 . The similarity is basically understood by the change of electron numbers inside the Ferm i surfaces on the basis of a rigid-band picture. We discuss our theoretical Ferm i surfaces with the dH vA experimental results on N pTG a_5 .

KEYW ORDS: Relativistic linear APW method, Fermi surface, Neptunium compounds, Plutonium compounds, Americium compound

1. Introduction

Recently electronic properties of actinide compounds have attracted renewed attention in the research eld of condensed matter physics. Am ong num erous kinds of actinide compounds, the group of materials with H oC oG a₅type tetragonal crystal structure, frequently referred to as 115", has been intensively investigated both from experimental and theoretical sides. A characteristic trend in the recent investigation of actinide compounds has been a rapid expansion of the research frontier from uranium to transuranium materials, typically found in a series of 115 system s, U -, N p-, P u-, and Am -115.

First let us brie y survey the properties of U-115. For several transition m etal ions T, UTGa₅ are antiferrom agnetic (AF) m etals or Pauliparam agnets.¹⁽¹²⁾ Am ong them, neutron scattering experim ents have revealed that UN iGa₅ exhibits the G-type AF phase, while UPdGa₅ and UPtGa₅ have the A-type AF state.^{8,12)} Note that G-type indicates a three-dimensional Neel state, while A-type denotes a layered AF structure in which spins align ferrom agnetically in the ab plane and AF along the caxis.On the other hand, for T = Co, Rh, Ir, Fe, Ru, and O s, m agnetic susceptibility is alm ost independent of tem – perature, since these are Pauli param agnets. It is quite interesting that the m agnetic structure is di erent for U – 115 com pounds which di er only by the substitution of transition m etal ions.

Now we move on to transuranium 115 com pounds. The rapid progress in the research from uranium to transuranium systems has been triggered by the discovery of superconductivity of Pu-115 com pound PuC oG a_5 .^{13,14}) It has been reported that the superconducting transition

tem perature T_c of PuC oG a_5 is 18.5K, which is am azingly high value even com pared with other well-known interm etallic com pounds. The coe cient of electronic speci c heat is estimated as = 77m J/m ol K, moderately enhanced relative to that for norm alm etals, suggesting that PuC oG a_5 should be heavy-ferm ion superconductor. In PuRhG a_5 , superconductivity has been also found.¹⁵ A lthough the value of T_c = 8.7K is lower than that of PuC oG a_5 , it is still high enough compared with other heavy-ferm ion superconductors. A nother Pu-115 m aterial, PuIrG a_5 , has been also synthesized, but at least up to now, superconductivity has not been found.¹⁶ In a bulk sample, AF m agnetic order has been suggested at low tem peratures, while the experimental results have not yet converged due to a problem of sample quality.

Recently Np-115 com pounds NpTG a_5 (T = Fe, Co, and N i) have been synthesized and several kinds of physical quantities have been successfully measured.^{17{25}} Especially, the de Haas-van Alphen (dHvA) e ect has been observed in NpN iG a_5 , 18 which is the rst observation of dHvA signal in transuranium com pounds. For NpC oG a5 and NpRhGa5, the dHvA oscillations have been also detected and plural number of cylindrical Ferm i surfaces are found.^{20,21)} For NpFeG a_5 , the magnetic moment at Fe site has been suggested in neutron scattering experim ents²⁵⁾ and it has been also detected by ⁵⁷Fe Mossbauer spectroscopy.²⁴⁾ The magnetic structure of N p-115 com pounds also depends sensitively on transition metalion:^{22,25)} G-AF for NpN iG a₅, A-AF for NpC oG a₅, and C-AF for NpFeGa5. Here C-type indicates a situation in which the ferrom agnetic chains along the c axis are antiferrom agnetically coupled in the ab plane.

Note also that in the neutron scattering experiment for NpNiGa₅, the G-AF peak due to canted magnetic moments of Np ions grows after the FM transition occurs.^{22,25)} It is characteristic of U-115 and Np-115 com - pounds that the magnetic properties are sensitive to the choice of transition m etal ions.

Q uite recently, the experim ental research on actinide 115 system s has been further developed and the frontier has reached am ericium compound AmCoGa₅.²⁶⁾ Interestingly enough, from the resistivity measurement, superconductivity has been suggested to occur below 2K, but unfortunately, it has not been con rm ed yet by other experimental techniques, mainly due to the di-culty caused by self-heating e ect. It may be interesting to consider a possibility of superconductivity in Am-115 also from the theoretical view point.

In order to elucidate the mechanism of superconductivity and magnetism of such actinide compounds, it is necessary to develop a m icroscopic theory based on an appropriate f-electron model. A prescription to construct a microscopic f-electron model has been obtained on the basis of a j-j coupling scheme.²⁷⁾ The spirit of the prescription is that the many-body e ect is further included into the band-structure calculation results. In actual calculations, since the energy dispersion obtained by the band-structure calculations are very complicated, the felectron kinetic term is simply reconstructed by using a tight-binding approximation based on the j-j coupling scheme so as to reproduce the band structure around the Ferm i energy. Here we note that all 5f electrons are assumed to be itinerant. Note also that it is quite natural to use the j-j coupling scheme for the construction of the m icroscopic f-electron m odel, since the total angularm om entum j is the label for one-electron state in the relativistic band-structure calculations in which the D irac equations are directly solved.

By applying the prescription to uranium compound such as U-115, it has been clari ed that electronic structure of uranium compounds is e ectively described by a two-orbital Hubbard model based on the j-j coupling schem e.²⁸⁾ W ith increasing f-electron number, it has been pointed out that this two-orbital Hubbard model can be also applied to some neptunium and plutonium compounds.For instance, quite recently, magnetic structure of Np-115²⁹⁾ and octupole ordering of NpO₂³⁰⁾ have been discussed based on the two-orbital Hubbard model.

A lthough it is important to develop the microscopic analysis of actinide compounds based on the simple felectron model, close attention should be always paid to correct information about the electronic properties around the Ferm i energy obtained by the relativistic band-structure calculations. Those two types of researches, microscopic analysis of the simple f-electron model and band-structure calculations, should be com – plementary to each other in order to make signi cant progress in our understandings on magnetism and superconductivity of actinide compounds.

In this paper, we study electronic properties of neptunium, plutonium, and americium compounds such as NpTG a_5 , PuTG a_5 , and AmCoG a_5 by using a relativistic linear augmented-plane-wave (RLAPW) method with the one-electron potential in the local-density approxim ation (LDA). We observe that the energy bands in the vicinity of Ferm i level are given by the large hybridization between 5f and Ga 4p electrons in actinide 115 com pounds. For PuTG a5, several cylindrical sheets of Ferm i surfaces with large volume are found in comm on for T = Co, Rh, and Ir. For Np-115, we nd that the Ferm isurfaces of NpFeG a5, NpC oG a5, and NpN iG a5 are sim ilar to those of UC oG a_5 , UN iG a_5 , and PuC oG a_5 , respectively. It is also found that the Ferm i surfaces of Am C oG a5 are rather sim ilar to those of PuC oG a5. Basically, the sim ilarity is understood by the rigid-band nature of the 115 structure, since the topology of the Ferm i surfaces in the band-structure calculations seems to depend on the sum of f-electron number of actinide ions and d-electron number of transition m etal ions.

The organization of this paper is as follows. In Sec. 2, we brie y explain the method of our band-structure calculations and lattice parameters for PuTG a_5 , NpTG a_5 , and AmCoGa₅. In Sec. 3, we show the results for electronic band structure and the Ferm i surfaces of PuTG a_5 (T=Co, Rh, and Ir), NpTG a_5 (T=Fe, Co, and Ni), and AmCoGa₅. In Sec. 4, we will discuss our present results of Pu-, Np-, and Am -115 m aterials in comparison with that of UCoGa₅. We also discuss the dHvA results on NpTGa₅ from the band-theoretical view point. Finally, in Sec. 5, we will sum marize this paper.

2. M ethod of B and C alculation

In order to calculate the electronic energy band structure of transuranium com pounds, in general, it is necessary to include relativistic e ects such as relativistic energy shifts, relativistic screening e ects, and spin-orbit interaction.³¹⁾ Based on the Dirac equation, such relativistic e ects can be fully taken into account in the energy band structure calculation.³²⁽³⁴⁾ Am ong several kinds of the band-structure calculation techniques, in this paper we adopt the RLAPW method.³⁵⁾ The exchange and correlation potential is considered within the LDA, while the spatial shape of the one-electron potential is determ ined in the mun-tin approximation. The self-consistent calculation is performed by using the lattice constants which are determ ined experimentally. It is stressed that all 5f electrons in PuTGa5, NpTGa5, and Am CoG a5 are assumed to be itinerant in our bandstructure calculations.

In Fig.1, we show the H oC oG a_5 -type tetragonal crystal structure which belongs to the space group P 4/m m m (N o. 123) and D $_{4h}^1$. N ote that one m olecule is contained perprim itive cell. In the H oC oG a_5 -type tetragonal structure, positions of atom s in the unit cell are given by (0, 0, 0) for actinide atom, (0, 0, 1/2) for transition m etal atom, (1/2, 1/2, 0) for G a atom at 1c site, and (0, 1/2, 1/2, 0)

z) for G a atom at 4i site, where z is a parameter determ ined from X-ray di raction experiments and the labels for atom s are referred in Fig. 1. The lattice constants, a and c, and the z parameters for NpTG a_5 , PuTG a_5 , and Am C oG a_5 are listed in Tables I and II.

The iteration process for solving the Dirac oneelectron equation starts with the crystal charge density that is constructed by superposing the

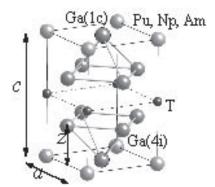


Fig. 1. Crystal structure of PuTG a_5 , NpTG a_5 and AmCoG a_5 .

Table I. Lattice constants and z parameter of NpFeG a_5 , NpC oG a_5 and NpN iG a_5 determ ined experimentally. $^{18,\,19)}$

	NpFeGa5	N pC oG a ₅	NpN 1Ga5
а	4.257 A	4.237 A	4.231 A
С	6.761 A	6.787 A	6.783 A
z	0.3011	0.310	0.3135

Table II. Lattice constants and z parameters of PuCoGa5, PuRhGa5, PuIrGa5, and AmCoGa5 determined experimentally $^{13,15,16,26)}$

	PuCoGa ₅	P uR hG a ₅	PuIrGa ₅	AmCoGa ₅
а	4.232 A	4.301 A	4.324 A	4.233 A
С	6.786 A	6 . 856 A	6.817 A	6 . 823 A
z	0.312	0.306	0.302	0.3106

Table III. The spin-orbit splitting obtained in the relativistic atom ic calculation. Energy unit is milli-Ryd. and 1 Ryd = 13.6 eV .

Pu 5f	Pu 6d	Np 5f	Np 6d	Am 5f	Am 6d
80	37	70	38	90	36
Fe 3d	Co 3d	Ni3d	Rh 4d	Ir 5d	Ga4p
11	13	18	29	90	7

relativistic atom ic charge densities for neutral $Pu([Rn]5f^{5}6d^{1}7s^{2}),$ $Np([Rn]5f^{4}6d^{1}7s^{2}),$ atom s Am ($\mathbb{R}n$]5f⁶6d¹7s²), Fe($\mathbb{A}r$]3d⁶4s²), Co($\mathbb{A}r$]3d⁷4s²), $Ni([Ar]3d^84s^2)$, $Rh([Kr]4d^85s^1)$, $Ir([Xe]4f^{14}5d^76s^2)$, and Ga(Ar]3d¹⁰4p¹4s²), where [Rn], [Kr], [Ke], and [Ar] symbolically indicate the closed electronic con guration for radon, krypton, xenon, and argon, respectively. In the calculation for the atom s, the same exchange and correlation potential are used as for the crystal. We assume that the Rn core state except the $6p^6$ state for Pu, Np, and Am, the Kr core state for Rh, the Xe core state for Ir, the Ar core state for Co, and the Ar core state for Ga are unchanged during the iteration. Namely, the frozen-core approximation is adopted for these core states in the calculation for the crystal. The values of the spin-orbit splitting in the relativistic atom ic calculation are listed in Table III.

In each iteration step for the self-consistent calculation

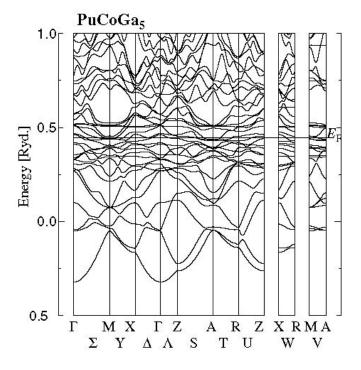


Fig. 2. Energy band structure for PuC oG a_5 calculated by using the self-consistent RLAPW $\,$ m ethod.E $_F$ indicate the position of the Ferm i level.

processes, a new crystalcharge density is constructed using eighteen k points, which are uniform ly distributed in the irreducible 1/16 part of the Brillouin zone. At each k in the Brillouin zone, 431 plane waves are adopted under the condition $j_k + G j 4:4(2 = a)$ with G the reciprocal lattice vector and angular momentum up to $j_{max} = 8$ are taken into account.

3. Band Calculation Results

3.1 Results for Pu-115

First let us discuss the calculated results for Pu-115 compounds, since PuCoG a_5 and PuRhG a_5 have been recently focused as \high-T_c" f-electron superconductors. Note that a part of the results of PuCoG a_5 has been published.³⁶⁾ B and-structure calculation results for PuTG a_5 (T=Co, Rh, and Ir) were also reported by another group.^{37,38)}

3.1.1 PuCoGa₅

In Fig. 2, we depict the energy band structure along the symmetry axes in the Brillouin zone in the energy region from 0.5 Ryd. to 1.0 Ryd. Note here that the three Pu 6p and twenty- ve G a 3d bands in the energy range between 1.0 Ryd. and 0.6 Ryd. are not shown in Fig. 2, since those bands are irrelevant to the present discussion. The Ferm i level E_F is located at 0.446 Ryd. and in the vicinity of E_F , there occurs a hybridization between the Pu 5f and G a 4p states. A round E_F near M point, the at 5f bands split into two groups, corresponding to the total angular momentum j=5/2 (lower bands) and 7/2 (upper bands). The magnitude of the splitting between those groups is estimated as 1.0 eV, which is alm ost equal to the spin-orbit splitting in the atom ic 5f state.

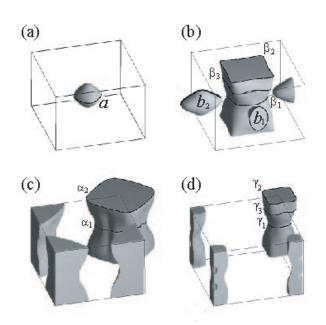


Fig. 3. Calculated Ferm i surfaces of PuC oG a_5 for (a) 15th band hole sheets, (b) 16th band hole sheets, (c) 17th band electron sheets, and (d) 18th band electron sheets. The center of the B rillouin zone is set at the point. We also show various kinds of extrem al cross section of the Ferm i surface.

Table IV. The number of valence electrons for PuCoG a_5 in the PuAPW sphere, the CoAPW sphere, and the GaAPW sphere partitioned into angular momenta.

	s	р	d	f
Рu	0.39	6.15	1.81	5.24
Со	0.43	0.44	7.46	0.01
G a (1c)	0.95	0.69	9.92	0.01
G a (4i)	3.73	2.82	39.75	0.06

The number of the valence electrons in the APW sphere is partitioned into the angular momenta as listed in Table IV. There are 8.17 valence electrons outside the APW sphere in the primitive cell. The total density of states at E_F is evaluated as N (E_F) = 97.3 states/Ryd cell. By using this value, the theoretical speci c heat coefcient $_{\rm band}$ is estimated as 16.9 mJ/K² mol. We note that the experimental electronic speci c heat coefcient $_{\rm exp}$ is 77 mJ/K² mol.³ We de ne the enhancement factor for the electronic speci c heat coe cient as $= _{\rm exp} = _{\rm band}$ 1, and in the present case, we obtain = 3.6. The disagreement between $_{\rm band}$ and $_{\rm exp}$ values is ascribed to electron correlation e ect and electron-phonon interactions, which are not fully taken into account in the present LDA band theory.

Now let us discuss the Ferm i surfaces of $PuC \circ Ga_5$. In Fig. 2, the lowest fourteen bands are fully occupied. The next four bands are partially occupied, while higher bands are empty. Namely, 15th, 16th, 17th, and 18th bands crossing the Ferm i level construct the hole or electron sheet of the Ferm i surface, as shown in Fig. 3. The Ferm i surface from the 15th band consists of one hole sheet centered at the point. The 16th band has two

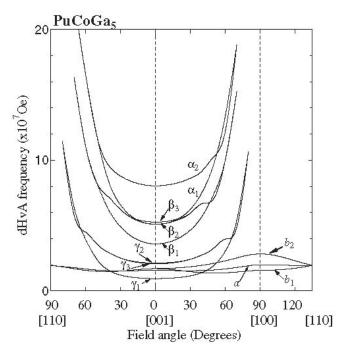


Fig. 4. A ngular dependence of the theoretical dH vA frequency in PuC oG a_5 . The labels of the branches are referred in Fig. 3.

kinds of sheets, as shown in Fig.3 (b). One is a set of sm all hole pockets, each of which is centered at the X point. A nother is a large cylindrical hole sheet which is centered at the point. The 17th band forms a large cylindrical electron sheet which is centered at the M point. The 18th band has a slender cylindrical electron sheet which is also centered at the M point. These electron sheets are characterized by two-dimensional Ferm i surfaces. The number of carriers contained in these Ferm isurface sheets are 0.040 holes/cell, 0.563 holes/cell, 0.519 electrons/cell, and 0.084 electrons/cell in the 15th, 16th, 17th, and 18th bands, respectively. The total number of holes is equal to that of electrons, which represents that P uC oG a_5 is a compensated m etal.

Note that the Ferm i surfaces of PuTGa₅ are similar to those of CeTIn₅.³⁹⁾ This similarity can be understood based on the electron-hole conversion relation in the j-j coupling scheme,³⁶⁾ since one f electron is included in the j= 5/2 sextet for Ce³⁺ ion, while vef electrons are contained for Pu³⁺ ion.

In Fig. 3, various kinds of extrem alorbits are depicted on the Ferm i surfaces. Am ong them, a denotes an orbit running around the small closed hole sheet centered at the point in the 15th band, while b_1 and b_2 indicate a couple of dH vA frequency branches which originate from the 16th hole sheets and exist in the narrow range from 0.015 M O e and 0.03 M O e. Its center is located at the X point. On the other hand, 1 and 2 are the orbits running around the cylinder along the V axis in the 17th band, while 1, 2, and 3 are the orbits running around the cylinder along the axis in the 16th band. Finally, 1, 2, and 3 denote the orbits running around the cylinder along the V axis in the 18th band. These orbits exist in the large range of angles in the vicinity of the [001] direction.

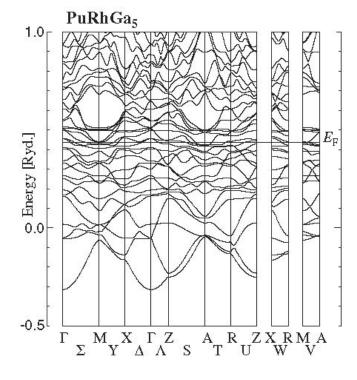


Fig. 5. Energy band structure for $P\,uR\,hG\,a_5$ calculated by using the self-consistent RLAPW $\,m$ ethod.

Table V. The number of valence electrons for PuRhGa₅ in the PuAPW sphere, the RhAPW sphere, and the GaAPW sphere partitioned into angular momenta.

	s	р	d	f
Рu	0.33	6.16	1.85	5.22
Rh	0.35	0.35	7.38	0.02
G a (1c)	0.99	0.75	9.94	0.01
G a (4i)	3.73	2.84	39.77	0.07

In Fig. 4, we show the angular dependence of the theoretical dHvA frequency in PuCoGa5. The area of the extrem al cross section of the Ferm i surface A is related to the dHvA frequency F by the well-known formula F = (c - 2)A. The Ferm i surface produces m any dH vA frequencies in the wide frequency range between 0.01 MOe and 220 MOe, as shown in Fig. 4. The sm all hole sheet in the 15th band possesses dHvA frequencies in the range between 0.015 M O e and 0.02 M O e. The Ferm i surface in the 16th, 17th, and 18th band possesses m any extrem al cross section in the lim ited range of angles because of its rugged shape. The dHvA experiments on Pu-115 com pounds have not yet been carried out due to several experim ental di culties, but we believe that such experiments will be done in near future. On that occasion, the present theoretical results will be helpful for the experim entalists.

3.1.2 PuRhGa₅

Let us move to another superconducting Pu-115 m aterial PuRhG a_5 . In Fig. 5, we depict the energy band structure and the Ferm i energy E_F is located at 0.436 Ryd. Narrow Pu 5f-bands just above E_F are split into two subbands by the spin-orbit interaction. A hybridiza-

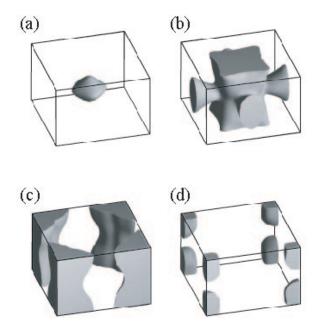


Fig. 6. Calculated Ferm is urfaces of PuRhG $a_5\,$ for (a) 15th band hole sheets, (b) 16th band hole sheets, (c) 17th band electron sheets, and (d) 18th band electron sheets.

tion between the Pu 5f state and Ga 4p state occurs in the vicinity of E_F also for PuRhGa₅. In Table V, we list the number of the valence electrons in the APW sphere distributed into the angular momenta. There are 8.31 valence electrons outside the APW sphere in the prim – itive cell. The theoretical electronic speci c-heat coe – cient _{band} is 13.2 m J/K² m ol, which is sm aller than that of PuC oG a₅.

Since 15th, 16th, 17th, and 18th bands are partially occupied, these four bands construct the Ferm i surface, as in the case of PuC oG a_5 . The hole and electron sheets of the Ferm i surface in PuRhG a_5 are shown in Fig. 6. The Ferm i surface from the 15th band consists of one hole sheet centered at the point. The hole sheet centered at the point in the 16th band is shown in Fig. 6 (b). This Ferm i surface possesses the crossed arm s, which are connected like a jungle-gym to the next B rillouin zone. The 17th band has a cylindrical electron sheet centered at the M point. The Ferm i surface from the 18th band consists of one hole sheet centered at the M point. The Ferm i surface from the 18th band consists of one hole sheet centered at the A point.

The number of carriers contained in these Ferm isurface sheets are 0.040 holes/cell, 0.627 holes/cell, 0.594 electrons/cell, and 0.073 electrons/cell in the 15th, 16th, 17th, and 18th bands, respectively. The total number of holes is equal to that of electrons, since PuRhG a_5 is also a compensated m etal.

3.1.3 PuIrG a₅

Now we discuss the electronic properties of yet another Pu-115 com pound. In Fig. 7, the energy band structure for PuIrG a_5 in the vicinity of the Ferm i energy E_F is shown along high-symmetry axes in the Brillouin zone. The Ferm i energy E_F is located at 0.453 Ryd. The band

-0.5L

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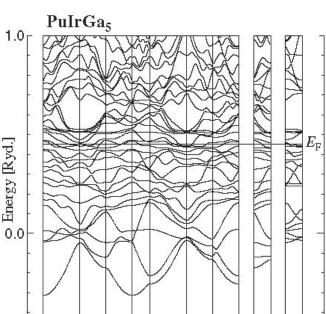


Fig. 7. Energy band structure for PuIrG a_5 calculated by using the self-consistent RLAPW method. E_F indicate the position of the Ferm i level.

 $M_{Y} \Lambda_{\Lambda} \Gamma_{\Lambda} Z$

A R Z X R MA S T U W V

Table VI. The number of valence electrons for PuIrGa5 in the PuAPW sphere, the IrAPW sphere, and the GaAPW sphere partitioned into angular momenta.

_	S	р	d	f
Рu	0.36	6.13	1.72	5.26
Ir	0.52	0.38	6.93	0.02
G a (1c)	1.01	0.78	9.96	0.01
G a (4i)	3.71	2.72	39.76	0.06

structure around the Ferm ienergy is alm ost the same as those of PuC oG a_5 and PuRhG a_5 . In Table V I, we show the number of the valence electrons in the APW sphere, which are partitioned into the angular momenta. There are 8.64 valence electrons outside the APW sphere in the primitive cell. In each Pu APW sphere, 5.26 electrons with the 5f symmetry are contained. The theoretical electronic speci c-heat coe cient band is 11.5 m J/K² m ol, which is smaller than that of PuRhG g.

The Ferm i level crosses the 15th, 16th, 17th, and 18th bands, which produce various hole and electron sheets of the Ferm i surface. The hole and electron sheets of the Ferm i surface in PuIrG a_5 are shown in Fig. 8. A gain we see that the Ferm i surface structure is quite similar to that of PuC oG a_5 . The Ferm i surface from the 15th band consists of one hole sheet centered at the point. The 16th band has a large cylindrical hole sheet which is centered at the point and two equivalent sm all hole pockets at the X point. The 17th band has a large electron sheet which is open in the [001] direction and boks like a cylinder running along the V axis. The Ferm i surface from the 18th band consists of one hole sheet centered at the A point.

(d)

Fig. 8.	Calcu	lated	Fer	m i su:	rfaces	ofPul	rG a	5 for	(a) 15	oth band
hole s	heets,	(b) 1	l6th	band	hole	sheets,	(C)	17th	band	electron
sheets, and (d) 18th band electron sheets.										

Table V II. The number of valence electrons for N pC oG a₅ in the N p A PW sphere, the C o A PW sphere, and the G a A PW sphere partitioned into angular momenta.

S	р	d	f
0.32	6.11	1.91	4.17
0.41	0.43	7.49	0.01
0.98	0.73	9.93	0.01
3.75	2.90	39.75	0.06
	s 0.32 0.41 0.98 3.75	0.32 6.11 0.41 0.43 0.98 0.73	0.32 6.11 1.91 0.41 0.43 7.49 0.98 0.73 9.93

The number of carriers contained in these Ferm isurface sheets are 0.025 holes/cell, 0.579 holes/cell, 0.537 electrons/cell, and 0.067 electrons/cell in the 15th, 16th, 17th, and 18th bands, respectively. The total number of holes is equal to that of electrons, again indicating that P uIrG a_5 is a compensated m etal.

Am ong three Pu-115 com pounds, it has been found that there is no essential di erences in the Ferm i surface structure, when Co is substituted by Rh and Ir. The energy scale of the band-structure calculation is considered to be too large to detect the sm all change in the Ferm i surface structure am ong three Pu-115 m aterials.

3.2 Results for Np-115

Let us turn our attention to Np-115 com pounds. It is quite in pressive that NpTG a_5 with T = Fe, Co, Ni, and Rh have been synthesized and several kinds of physical quantities have been measured. Especially, the dH vA signals have been successfully detected and the com parison with band-calculation results is in portant. Note that a part of the results on NpC oG a_5 has been reported.^{36,38)}

(a)

(c)

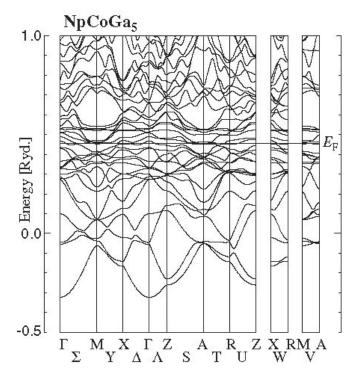


Fig. 9. Energy band structure for NpC oG a_5 calculated by using the self-consistent RLAPW method. E_F indicate the position of the Ferm i level.

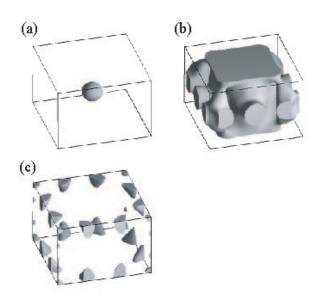


Fig. 10. Calculated Ferm is urfaces of NpC oG $a_5\,$ for (a) 15th band hole sheets, (b) 16th band hole sheets, and (c) 17th band electron sheets.

3.2.1 N pC oG a₅

F irst let us show the results of N pC oG a_5 . F igure 9 indicates the energy band structure calculated for N pC oG a_5 , in the energy range from 0.5 Ryd.to 1.0 Ryd.N ote that the three N p 6p and twenty- ve G a 3d bands in the energy range between 1.0 Ryd. and 0.6 Ryd. are not shown in F ig. 9. The Ferm i level E_F is located at 0.456 Ryd. and in the vicinity of E_F, there occurs a hybridiza-

tion between the Np 5f and G a 4p states, sim ilar to the case of PuTG a_5 and UTG a_5 . The hybridization between 5f and G a 4p electrons is considered to be a comm on feature in actinide 115 m aterials. In Fig. 9, the at bands in the narrow energy range just above E_F consist dom inantly of the Np f states. Above E_F near M point, the at 5f bands split into two groups, corresponding to the total angular momentum j=5/2 (lower bands) and 7/2 (upper bands). The magnitude of the splitting between those groups is estimated as 0.95 eV, a little bit sm aller than that of Pu, which is alm ost equal to the splitting in the atom ic 5f state.

The number of the valence electrons in the APW sphere is listed in Table V II. There are 8.11 valence electrons outside the APW sphere in the primitive cell and each Np APW sphere contains about 4.17 electrons in the f state. The total density of states at E_F is evaluated as N (E_F) = 230.4 states/Ryd cell. By using this value, the theoretical speci c heat coe cient band is estimated as 39.9 m J/K² m ol. Since the experimental electronic speci c heat coe cient exp is 60.0 m J/K² m ol.⁹⁾ the enhancement factor is found to be 0.5.

Next we discuss the Ferm i surfaces of NpC oG a_5 . In Fig. 9, the lowest fourteen bands are fully occupied. The next three bands are partially occupied, while higher bands are empty, indicating that 15th, 16th, and 17th bands crossing the Ferm i level form the hole or electron sheet of the Ferm i surface, as shown in Fig. 10. The Ferm i surface from the 15th band consists of sm all hole sheets centered at the point. The 16th band constructs a large cylindrical hole sheet centered at the point, which exhibits a complex network consisting of big \arm s" along the edges of the B rillouin zone, as observed in Fig. 10(b). The 17th band constructs a shown in Fig. 10(c).

The number of carriers contained in these Ferm isurface sheets are 0.015 holes/cell, 0.996 holes/cell, and 0.063 electrons/cell in the 15th, 16th, and 17th bands, respectively. The total number of holes is not equal to that of electrons, indicating that N pC oG a_5 is an uncom – pensated m etal.

3.2.2 N pN iG a₅

Next we discuss the electronic properties of N pN iG a₅. In Fig. 11, the energy-band structure is depicted. We should note that there is no qualitative di erence in the energy-band structure between N pC oG a₅ and N pN iG a₅, but the position of E_F is a little bit shifted as $E_F = 0.464$ Ryd. The number of the valence electrons in the APW sphere is listed for each angularm on enta in Table V III. There are 8.44 valence electrons outside the APW sphere in the primitive cell and each Np APW sphere contains about 4.15 electrons in the f state. The total density of states is calculated at E_F as N (E_F) = 171:9 states/R yd.cell, leading to $_{band} = 29.8 \text{ mJ/K}^2 \text{ m ol. N ote that } _{exp} = 100.0 \text{ mJ/K}^2 \text{ m ol for NpN iG g, leading to } = 2.4.$

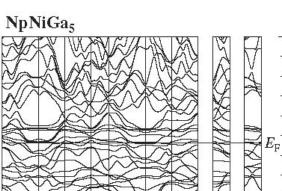
In Fig. 12, we show the Ferm isurfaces form ed by 15th, 16th, 17th, and 18th bands. The Ferm isurface from the 15th band includes one sm all hole sheet centered at the point. The 16th band constructs a large cylindrical 1.0

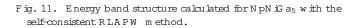
Energy [Ryd.]

0.0

-0.5L

Г





 $M_{Y} \begin{array}{c} X_{A} \Gamma_{A} \overline{Z} \\ Y \end{array} \begin{array}{c} A \\ A \end{array} \begin{array}{c} \overline{X} \\ S \end{array} \begin{array}{c} \overline{X} \\ T \end{array} \begin{array}{c} \overline{X} \\ \overline{U} \end{array} \begin{array}{c} \overline{X} \\ W \end{array} \begin{array}{c} \overline{X} \\ W \end{array} \begin{array}{c} \overline{X} \\ V \end{array} \begin{array}{c} \overline{X} \\ V \end{array} \begin{array}{c} \overline{X} \\ \overline{X} \end{array} \begin{array}{c} \overline{X} \\ \overline{X} \end{array} \begin{array}{c} \overline{X} \\ \overline{X} \end{array} \begin{array}{c} \overline{X} \\ \overline{X} \end{array} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array} \begin{array}{c} \overline{X} \\ \overline{X} \end{array} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\end{array}{}} \end{array}{\begin{array}{c} \overline{X} \end{array}{\end{array}{}} \begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\end{array}{}} \end{array}{\begin{array}{c} \overline{X} \end{array}{\end{array}{}} \end{array}{\begin{array}{c} \overline{X} \\ \overline{X} \end{array}{\end{array}{}} \end{array}{\end{array}{}$

Table V III. The number of the valence electrons for N pN iG a_5 in the N p A PW sphere, the N i A PW sphere, and the G a A PW sphere partitioned into angular momenta.

d	f
2 1.91	4.15
9 8.39	0.01
7 9.92	0.01
9 39.73	0.05
	2 1.91 9 8.39 7 9.92

hole sheet centered at the point, while two equivalent smallhole sheets are centered at X points. The 17th band has a large electron sheet centered at the A point. This large electron sheet looks like a swelled square-cushion with bulges on surfaces. The 18th band has a small electron sheet. Each electron sheet lies across the V axis and looks like a cushion. If the 16th-band hole Ferm i surface of NpC oG a_5 is alm ost occupied by an electron and the volume of the 17th-band electron Ferm i surface is slightly enlarged, these Ferm i surfaces correspond to the 16th-band hole Ferm i surfaces and the 17th-band electron ones of NpN iG a_5 , respectively.

The numbers of carriers contained in these Fem is surface sheets are 0.006 holes/cell, 0.430 holes/cell, 0.427 electrons/cell, and 0.009 electrons/cell in the 15th, 16th, 17th, and 18th bands, respectively. The total number of holes is equal to that of electrons, indicating that NpN iG a_5 is a compensated m etal.

3.2.3 N pFeG a_5

Finally, let us discuss the electronic properties of NpFeG a_5 . In Fig. 13, the energy band structure along the symmetry axes in the Brillouin zone is shown. The Ferm i energy E_F is located at $E_F = 0.433$ Ryd. A gain we

(b)

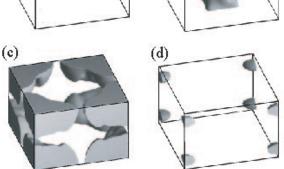


Fig. 12. Calculated Ferm is urfaces of N pN iG a_5 for (a) 15th band hole sheets, (b)16th band hole sheets, (c)17th band electron sheets and (d)18th band electron sheets.

Table IX. The number of the valence electrons for NpFeG $a_5\,$ in the Np APW sphere, the Fe APW sphere, and the Ga APW sphere partitioned into angular momenta.

	S	р	d	f
Np	0.32	6.04	1.79	4.13
Fe	0.40	0.38	6.40	0.01
G a (1c)	1.08	0.90	9.98	0.02
G a (4i)	3.85	2.92	39.79	0.06

observe that the electronic structure of N pFeG a_5 is sim – ilar to N pC oG a_5 , except for the location of the Ferm i level. The number of the valence electrons in the A PW sphere is listed in Table IX . There are 8.03 valence electrons outside the A PW sphere in the primitive cell and each N p A PW sphere contains about 4.13 electrons in the f state. The total density of states is calculated at $E_{\rm F}$ as N ($E_{\rm F}$) = 133:6 states/R yd cell, leading to $_{\rm band}$ = 23.1 m J/K 2 m ol.

We note that the lowest fourteen bands are fully occupied, the next two bands are partially occupied, and higher bands empty. Then, 15th and 16th bands construct the Ferm i surfaces, as shown in Fig. 14. These Ferm i-surface sheets are small in the size and closed in topology. Note that there exists no open orbit on any sheets. The numbers of carriers contained in these Ferm i-surface sheets are 0.094 holes/cell and 0.094 electrons/cell in the 15th and 16th bands, respectively. The total number of holes is equal to that of electrons, which m eans that NpFeG a_5 is a compensated m etal. Note that there are just 0.094 holes/cell and the compensating number of electrons, indicating that NpFeG a_5 is a sem in etal.

(a)

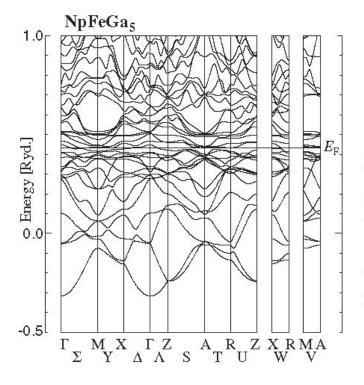


Fig. 13. Energy band structure calculated for N pFeG a_5 with the self-consistent RLAPW m ethod.

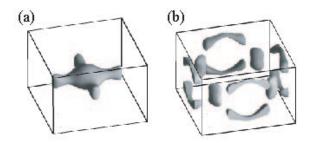


Fig. 14. Calculated Ferm is urfaces of N pFeG a_5 for (a) 15th band hole sheets and (b)16th band electron sheets.

3.2.4 Comment on NpTGa₅

Here we discuss sim ilarity and di erence am ong three Np-115 com pounds. For the purpose, let us exam ine the trend in the change of d electron number in transition m etal atom s. The numbers of electrons with the d character contained in the Fe, Co, and NiAPW spheres are 6.40, 7.49, and 8.39 in NpFeG a₅, NpC oG a₅, NpN iG a₅, respectively, indicating clearly that the number is increased by unity am ong three Np-115 com pounds. Since one m ore d electron is added to NpC oG a₅, the Ferm i level for NpN iG a₅.

To understand the change in the electronic properties am ong three Np-115 com pounds, it is useful to see the total density of states (DOS), as shown in Fig. 15. We should note that there is no qualitative di erence in the energy-band structure am ong Np-115 com pounds: The 5f bands are split into two subbands by the spin-

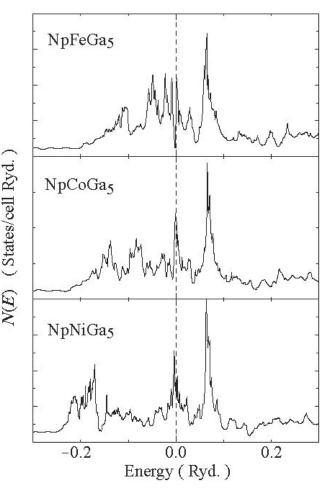


Fig. 15. Density of states for N pFeG a_5 , N pC oG a_5 and N pN iG a_5 . D ashed line indicates the Ferm i energy, from which the energy is measured.

orbit interaction and due to the hybridization between 5f and 4p electrons, nite DOS always appear at the Ferm i level, indicating that Np-115 com pounds are m etallic in our band-structure calculations. Note, how ever, that the peak structure in the DOS are located just at or near the Ferm ienergy in common with three Np com pounds. This fact m ay be related to the easy appearance of m agnetism in Np-115 m aterials. W hen the transition m etal atom is substituted, the position of E_F is a little bit shifted upward with increasing d electron in the order of NpFeG a_5 , NpC oG a_5 , and NpN iG a_5 .

3.3 Result for Am C oG a₅

Now we show our calculated result of the energyband structure of $Am C \circ Ga_5$ within the fram ework of the itinerant-electron m odel for the 5f electrons. In Fig. 16, we depict the energy band structure along the symmetry axes in the Brillouin zone in the energy region from

 $0.5~{\rm R}\,{\rm yd.}$ to $1.0~{\rm R}\,{\rm yd.}$ W e do not show the three Am 6p and twenty- veGa 3d bands in the energy range between

1:0 Ryd.and 0:6 Ryd.The Ferm i level E_F is located at 0.437 Ryd.and in the vicinity of E_F , there occurs a hybridization between the Am 5f and Ga 4p states.The number of the valence electrons in the APW sphere is partitioned into the angular momenta, as listed in Table X.There are 8.22 valence electrons outside the APW

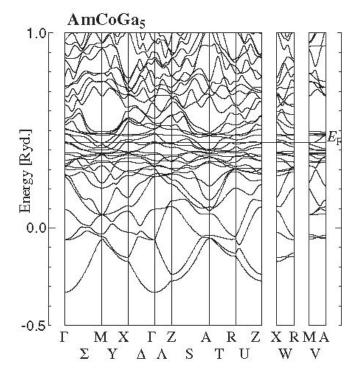


Fig. 16. Energy band structure for Am C oG a_5 calculated by using the self-consistent RLAPW method. E_F indicate the position of the Ferm i level.

Table X. The number of valence electrons for AmCoGa5 in the Am APW sphere, the CoAPW sphere, and the GaAPW sphere partitioned into angular momenta.

	S	р	d	f
Am	0.39	6.16	1.68	6.39
Со	0.43	0.42	7.45	0.01
G a (1c)	0.95	0.67	9.92	0.01
G a (4i)	3.73	2.77	39.75	0.05

sphere in the primitive cell. The total density of states at E_F is evaluated as N (E_F) = 62.8 states/Ryd.cell. By using this value, the theoretical speci c heat coe cient _{band} is estimated as 10.9 m J/K² m ol.

In Fig. 16, the lowest freen bands are fully occupied. The next four bands are partially occupied, while higher bands are empty. Namely, 16th, 17th, 18th, and 19th bands crossing the Ferm i level construct the hole or electron sheet of the Ferm i surface, as shown in Fig. 17. As shown in Fig. 17 (a), the Ferm isurface from the 16th band consists of two equivalent sm all hole sheets centered at the X points and one hole sheet centered at the point. It consist of eight small closed sheets which have the m irror-inversion symmetry with respect of f100g, f010g, and f001g planes lying between them . The 17th band has three kinds of sheets, as shown in Fig. 17 (b). One is a set of two equivalent electron-like pockets, each of which is centered at the R point. A nother is electron pocket centered at the Z point. There is also a large cylindrical electron sheet centered at the M point, which characterizes the two-dimensional Fermi surface. The 18th band has a slender cylindrical electron sheet which is also centered at the M point, as shown in Fig. 17 (c). The 19th band

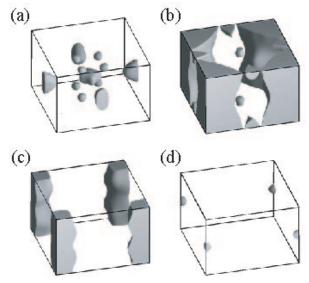


Fig. 17. Calculated Ferm isurfaces of Am C oG a_5 for (a) 16th band hole sheets, (b) 17th band hole sheets, (c) 18th band electron sheets, and (d) 19th band electron sheets.

constructs a very sm all electron sheet, which is centered at the M point, as shown in Fig. 17 (d). The number of carriers contained in these Ferm i-surface sheets are 0.048 holes/cell, 0.785 electrons/cell, 0.272 electrons/cell, and 0.0004 electrons/cell in the 16th, 17th, 18th, and 19th bands, respectively. The total number of holes is not equal to that of electrons, indicating that $Am CoG a_5$ is an uncom pensated m etal.

W e remark that the Ferm is urfaces of Am C oG a_5 seem to be similar to those of $PuCoGa_5$, since we can see the multiple two-dimensional cylindrical Ferm i-surface sheets with a constricted part around at M point. For a better understanding of the Ferm i surface, we attempt to explain the relationship between AmCoGa5 and PuCoGa5. On the basis of the itinerant 5f electron model, $A \mod C \ oG \ a_5$ has one more B loch electron per prim it ive cell in comparison with PuCoGa₅. Therefore, in AmCoGa₅, the Ferm i level shift upward, indicating that relatively the position of 5f bands m ove dow nw ard. As a result, we nd that the 15th-band hole sphere of $PuCoGa_5$ disappears and the size of the 16th-band hole sheet becom es sm aller. On the other hand, the sizes of the 17th-and 18th-band cylindrical electron sheets become large. Note that in Am CoG a5, a sm all electron sheet appears in the 19th band.

However, in the recent band-structure calculation result, O pahle et al. have found that the Ferm i surface structure of $Am CoG a_5$ is dierent from that of PuCoG a_5 .³⁸⁾ Although the gures for band structure and Ferm i surface of $Am CoG a_5$ were not shown in Ref. 38, their results for PuCoG a_5 have been found to be quite sim ilar to ours and thus, their Ferm i surfaces of $Am CoG a_5$ are considered to be dierent from ours. O ne reason for this discrepancy is the treatment of 5f electrons. Namely, we have treated itinerant 5f electrons, while O pahle et al. considered localized ones. In general, the tendency of localization of 5f electron in Am is stronger than that in Pu, but in actual compounds, it is di cult to determ ine which is the better approximation, localized or itinerant picture. It will be necessary to clarify which picture well explains the experimental results consistently.

Finally, let us comment on the electron finitial electron congurations in actinide atoms. In the present calculations, as we have mentioned in Sec. 2, we have considered the electron conguration of $(\mathbb{R}n]5f^{6}6d^{1}7s^{2})$ for Am atom. However, this conguration is not uniquely determined. For instance, it may be possible to start the calculation by using $(\mathbb{R}n]5f^{7}6d^{0}7s^{2})$. Also for Np-and Pu-115 compounds, we can consider other electron congurations such as Np $(\mathbb{R}n]5f^{5}6d^{0}7s^{2})$ and Pu $(\mathbb{R}n]5f^{6}6d^{0}7s^{2})$. In order to nalize the Fermi-surface structure of actinide 115 m aterials, it is necessary to perform carefully further calculations by changing the initial electron congurations for actinide ions. It is an important future task.

4. D iscussion

In the previous section, we have shown the bandstructure calculation results for PuTGa₅, NpTGa₅, and AmCoGa₅. In order to obtain deep insight into the electronic properties of these 115 compounds, it is useful to compare the results with the electronic energy band structure of UCoGa₅, as shown in Fig. 18.^{40,41} Note that three U 6p and twenty- ve Ga 3d bands are om itted. The Ferm i energy E_F is located at E_F = 0.461 Ryd. The total density of states at E_F of UCoGa₅ is calculated as N (E_F) = 48.4 states/Ryd.cell, which corresponds to $_{band} = 8.4 \text{ m J/K}^2 \text{ m ol.}$

In UC oG a_5 , the 15th and 16th bands form the Ferm i surfaces, as shown in Fig. 19. The Ferm i surfaces from the 15th band have one sheet centered at the point, two equivalent sheets centered at the X points, and the sheets across the S axis. Figure 19 (b) shows a set of the sixteen electron sheets of the Ferm i surfaces in the 16th band. Each electron sheet across the T axis boks like a cushion. The total number of holes is equal to that of electrons, which means that UC oG a_5 is a compensated m etal.

Except for details, we can observe that the sheets of the Ferm i surface of UC oG a_5 with small size and closed topology are similar to those of NpFeG a_5 (see Fig. 14). We also remark that N pC oG a_5 is considered to be UC oG a5 plus one more f-electron from the view point of the Ferm i surface topology, since the small-pocket parts are the rem nants of UC oG a_5 and the large-volum e Ferm i surface contains one additional electron. Interestingly enough, the Ferm i surfaces of UN iG a_5 ⁵⁾ are quite sim ilar to Fig. 10, since both of UN iG a_5 and NpC oG a_5 are regarded as $UC \circ Ga_5$ plus one more electron, if we simply ignore the di erence in the original character, d or f, of the additional one electron. Since NpC oG a5 is $UC \circ Ga_5$ plus one f-electron and NpFeG a_5 is regarded as NpC oG a₅ m inus one d-electron, the Ferm i surfaces of UC oG a₅ are sim ilar to NpFeG a₅.

Based on the discussion on the number of d and f electrons, we also point out that the Fermi surfaces

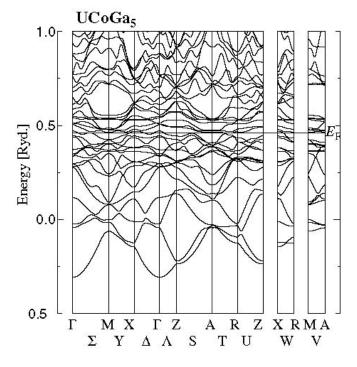


Fig. 18. Energy band structure calculated for $U\,C\,oG\,a_5$ with the self-consistent RLAPW m ethod.

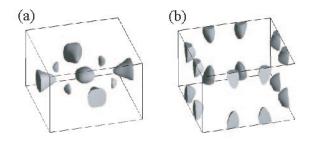


Fig. 19. Calculated Ferm i surfaces of UC oG as for (a) 15th band hole sheets and (b)16th band electron sheets.

of NpN iG a_5 should be similar to those of PuC oG a_5 , as shown in Figs. 3 and 12. However, it is clearly observed that two-dimensionality in the Ferm i surfaces of NpN iG a_5 becomes worse compared with those of PuC oG a_5 . This may be related to the reason why NpN iG a_5 is not superconducting, in spite of the same group with PuC oG a_5 in the electron number discussion.

The above phenom enology on the d- and f-electron num bers seem s to suggest that a rigid-band picture works for actinide 115 com pounds. This point can be partly validated due to the fact that the band structure of these com pounds is basically determ ined in common by hybridization between broad p bands and narrow f bands in the vicinity of the Ferm i level. B ased on the rigid-band picture, the electron band structure itself is not changed signi cantly, even when we change actinide and/or transition m etalions. Thus, just by counting the valence electrons of actinide and transition m etalions, we can easily deduce the Ferm i-surface topology, starting with the re-

sults of UC oG a₅.

It is interesting to compare the total DOS calculated for AnCoGa₅ (An=U, Np, Pu, and Am), as shown in Fig. 20. We again see that the structures of DOS are qualitatively in common with actinide 115 compounds except for details, when we change the actinide ions. In UCoGa₅, the Ferm ienergy is located in a valley, leading to the sm allDOS at E_F , consistent with a sem im etalbehavior. On the other hand, for NpCoGa₅, as mentioned in the previous section, the peak is located just at the Ferm ienergy. A fler including the e ect of electron correlation, m agnetic transition m ay easily occur in this case. For PuCoGa₅ and AmCoGa₅, we observe m oderate values of the DOS at the Ferm ienergy, consistent with the param agnetic m etallic phase.

It is noted that the numbers of electrons with the f sym m etry contained in the actinide APW sphere are, respectively, 32, 42, 52, and 6.4 for UC oG a_5 , NpC oG a_5 , $PuCoGa_5$, and $AmCoGa_5$, with increasing by unity as the atom ic number of actinide atom increases. This fact seem s to suggest that electrons are supplied to the unoccupied 5f bands of UC oG a_5 . N am ely, the change in the Ferm i surface structures am ong actinide 115 com pounds is basically understood by an upward shift of the Ferm i level on the rigid electronic bands. The same change occurs between $PuCoGa_5$ and $AmCoGa_5$. Note, however, that it is also in portant to specify the di erence am ong 115 com pounds. Especially, the change of the magnetic structure in Np-115 compounds as well as the appearance of m om ent at Fe ion in NpFeG a5^{22 (25)} is not claried by the present band-structure calculations. In order to understand these points, it is necessary to calculate not only the total DOS but also the partial DOS for dand f-electron component within our band-calculation program. It is one of future problem s.

Finally, let us discuss the dH vA experimental results on NpN iG a_5 ,¹⁸⁾ NpC oG a_5 ,²⁰⁾ and NpR hG a_5 ,²¹⁾ in com – parison with our theoretical Ferm i surfaces of Np-115. For NpN iG a_5 , A oki et al. have observed several sets of the dH vA frequency branches in the region of the order 10^7 O e, which have the cyclotron e ective masses from $1.8m_0$ to $4.9m_0$ in the magnetic- eld direction [100] and [001]. Here m₀ is the rest mass of a free electron. It is remarkable that the e ective masses greater than the freeelectron mass have been observed, because it in plies that the 5f electrons may be itinerant in NpN iG a_5 .

For NpC oG a_5 , a couple of cylindrical sheets of Ferm i surfaces with large volum e have been detected, while in our band-structure calculations, one cylindrical sheet is obtained, as shown in Fig. 10.N am ely, the dH vA results are not explained by the band calculation in the param – agnetic state. A possible explanation for this discrepancy is to consider the folding of Ferm i surfaces in the m agnetic B rillouin zone, since N pC oG a_5 exhibits the A -type AF structure with a N eel tem perature $T_N = 47K$. If the m agnetic unit cell is elongated along the [001] direction and doubled with respect to the chem ical unit cell as observed in UPtG a_5 ,¹¹⁾ a quasi-two dimensional Ferm i surface is m ore likely to appear due to the at magnetic B rillouin zone.

However, in actual dHvA experiments, due to the ap-

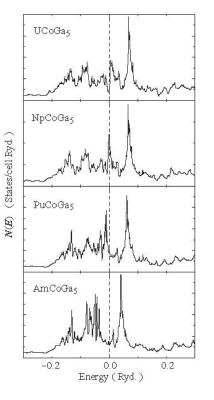


Fig. 20. Density of states for U C oG a_5 , N pC oG a_5 , P uC oG a_5 and A m C oG a_5 . D ashed line indicates the Ferm i energy.

plied magnetic eld, the system is not AF, but ferromagnetic. Thus, the above explanation cannot be simply applied to this case. In addition, quite recently, the dH vA experiments have been also performed for NpRhG a_5 , which is also A-type antiferrom agnet. In this material, four cylindrical sheets of Ferm i surfaces have been reported,²¹⁾ consistent with the folding of Ferm i surfaces of NpC oG a_5 in the magnetic B rillouin zone. Thus, it is experimentally con med that a couple of cylindrical sheets of Ferm i surfaces exist in NpC oG a_5 .

It may be true that the rigid-band picture cannot explain universally the band structure of actinide 115 com pounds, especially of Np-115 m aterials. How ever, a sim ple tight-binding approximation based on the j-j coupling scheme can reproduce a couple of cylindrical Fermi $surfaces_{r}^{29}$ by assuming that two of four 5f electrons in Np ion are active. In order to understand the dHvA experim ental results on the Ferm i surfaces, it is a correct direction to improve the band-structure calculations by considering the di erence in the degree of itinerancy among 5f electrons. In fact, it has been suggested that a couple of cylindrical Ferm i-surface sheets are obtained in the spin-orbital polarized band-structure calculation.⁴²⁾ Another way is an application of the fullpotentialm ethod to the fully relativistic band-structure calculations. Such an extension of the band-calculation m ethod is one of im portant future tasks.

5. Sum m ary

In this paper, we have applied the RLAPW m ethod to the self-consistent calculation of the electronic structure for PuTG a_5 , NpTG a_5 , and AmCoG a_5 on the basis of the itinerant 5f electron picture. It has been found that a hybridization between the 5f and G a 4p states occurs in the vicinity of E_F . We have calculated the dH vA frequencies for PuC oG a_5 for future experiments. The similarity in the Ferm i surface structure among actinide 115 com – pounds has been found to be understood based on the rigid-band picture, while the theoretical Ferm i surfaces of NpC oG a_5 are di erent from ones in the recent dH vA experimental results. For the purpose to understand this point, it is a challenging future problem to improve the band-calculation technique.

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